WHAT IS CLAIMED IS:

- An abrasive comprising a slurry comprising
- 2 a medium and cerium oxide particles dispersed in said medium
- 3 constituted of at least two crystallites and having crystal
- 4 grain boundaries.
- 1 2. The abrasive according to claim 1, wherein said
- 2 cerium oxide particles having crystal grain boundaries have
- 3 diameter with a middle value of from 60 nm to 1,500 nm.
- 3. The abrasive according to claim 1, wherein said
- cerium oxide particles having crystal grain boundaries have
- diameter with a middle value of from 100 nm to 1,200 nm.
- 1 4. The abrasive according to claim 1, wherein said
- 2 cerium oxide particles having crystal grain boundaries have
- 3 diameter with a middle value of from 300 nm to 1,000 nm.
- 1 5. The abrasive according to any one of claims 1 to
- 2 4, wherein said crystallites have diameter with a middle
- 3 value of from 5 nm to 250 nm.
- 1 6. The abrasive according to any one of claims 1 to
- 2 4, wherein said crystallites have diameter with a middle
- 3 value of from 5 nm to 150 nm.

- The abrasive according to claim 4, wherein said
- 2 crystallites have diameter with a middle value of from 10 nm
- 3 to 50 nm.
- 1 8. The abrasive according to claim 4, wherein said
- 2 crystallites have diameter with a middle value of from 50 nm
- 3 to 200 nm.
- 9. The cerium oxide abrasive according to any one of
- 2 claims 1 to 8, wherein said cerium oxide particles having
- 3 crystal grain boundaries have a maximum diameter not larger
- 4 than 3,000 nm.
- 1 10. The cerium oxide abrasive according to any one
- 2 of claims 1 to 9, wherein said crystallites have a maximum
- 3 diameter not larger than 600 nm.
- 1 11. An abrasive comprising a slurry comprising a
- 2 medium and abrasive grains having pores which are dispersed
- 3 in said medium.
- 1 12. The abrasive according to claim 11, wherein said
- 2 abrasive grains have a porosity of from 10% to 30% as
- 3 determined from the ratio of a true density measured with a
- 4 pycnometer to a theoretical density determined by X-ray
- 5 Rietvelt analysis.

- 1 13. The abrasive according to claim 11 or 12,
- 2 wherein said abrasive grains have a pore volume of from 0.02
- 3 cm^3/g to 0.05 cm^3/g as measured by the B.J.H. method.
- 1 14. The abrasive according to any one of claims 11
- 2 to 13, wherein said abrasive grains are cerium oxide
- 3 particles.
- 1 15. An abrasive comprising a slurry comprising a
- 2 medium and dispersed therein cerium oxide particles having a
- 3 bulk density not higher than 6.5 g/cm³.
- 1 16. The abrasive according to claim 15, wherein
- 2 said bulk density is from 5.0 g/cm³ to 5.9 g/cm³.
- 1 17. The cerium oxide abrasive according to any one
- 2 of claims 1 to 16, wherein said medium is water.
- 1 18. The cerium oxide abrasive according to any one
- 2 of claims 1 to 17, wherein said slurry contains a
- 3 dispersant.
- 1 19. The cerium oxide abrasive according to claim 18,
- 2 wherein said dispersant is at least one selected from a
- 3 water-soluble organic polymer, a water-soluble anionic
- 4 surfactant, a water-soluble nonionic surfactant and a

- 5 water-soluble amine.
- 1 20. The cerium oxide abrasive according to claim 19,
- 2 wherein said dispersant is a polyacrylic acid type polymer.
- 1 21. The abrasive according to claim 1, wherein;
- 2 cerium oxide particles with a diameter not smaller
- 3 than 1 μm occupies at least 0.1% by weight of the total
- 4 weight of the cerium oxide particles; and
- 5 said cerium oxide particles having crystal grain
- 6 boundaries have the nature of polishing a target member
- 7 while collapsing.
- 1 22. The abrasive according to claim 1, wherein said
- 2 cerium oxide particles having crystal grain boundaries have
- 3 the nature of polishing a target member while forming new
- 4 surfaces not coming into contact with any medium.
- 1 23. The abrasive according to claim 1, wherein the
- 2 content of cerium oxide particles having a particle diameter
- 3 not smaller than 0.5 μm after polishing, measured by
- 4 centrifugal sedimentation after a target member has been
- 5 polished, is in a ratio of not more than 0.8 with respect to
- 6 that content before polishing.
- 1 24. The abrasive according to claim 1, wherein

- 2 cerium oxide particle diameter at D99% by volume measured by
- 3 laser diffraction after a target member has been polished is
- 4 in a ratio of from 0.4 to 0.9 with respect to that particle
- 5 diameter before polishing.
- 1 25. The abrasive according to claim 1, wherein
- 2 cerium oxide particle diameter at D90% by volume measured by
- 3 laser diffraction after a target member has been polished is
- 4 in a ratio of from 0.7 to 0.95 with respect to that particle
- 5 diameter before polishing.
- 1 26. A method of polishing a target member,
- 2 comprising polishing a target member by the use of the
- 3 abrasive according to any one of claims 1 to 25.
- 1 27. The method of polishing a target member
- 2 according to claim 26, wherein said target member has a
- 3 strength higher than the grain boundary breaking strength of
- 4 the cerium oxide particles.
- 1 28. The method of polishing a target member
- 2 according to claim 26, wherein said target member is a
- 3 semiconductor chip on which a silica film has been formed.
- 1 29. A process for producing a semiconductor device,
- 2 comprising the step of polishing a semiconductor chip on

- which a silica film has been formed, by the use of the
- 4 abrasive according to any one of claims 1 to 25.